

## **Rotary Detection Sensor with Optical Reflection Type**

### **■FEATURES**

- Miniature, thin package: 2.6mm x 2.5mm x 0.8mm
- Digital two outputs type: A/B phases
- Resolution: 50.8LPI \* Lines Per Inch (2LPmm \* Lines Per mm)
- Recommendation strip width: 0.25mm
- Pb free soldering re-flowing permitted: 255°C, 2times
- Halogen free, Pb free
- Compliant with RoHS directive

## **■**APPLICATION

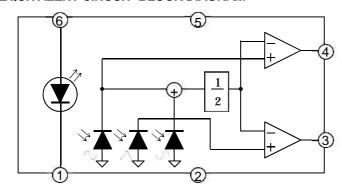
- Rotation detection of focus ring
- Rotation detection of the operation dial
- Rotation detection of the encoder plate

## **■GENERAL DESCRIPTION**

NJL5820R is the compact surface mount type photo reflector, which is built in a high Brightness Infrared LED and PDIC. It can obtain two-phase(A,B) digital signals with the recommended striped reflector.

It is the optimum sensor for various kinds of rotation detection, which can contribute to low power consumption of the set and simplification of the design.

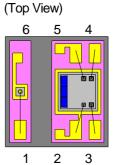
#### ■ EQUIVALENT CIRCUIT · BLOCK DIAGRAM



- 1. Cathode (LED)
- 2. GND
- 3. Vout2
- 4. Vout1
- 5. V<sub>CC</sub>
- 6. Anode (LED)

## **■ PIN CONFIGURATION**

PIN No	NAME	FUNCTION
1	Cathode (LED)	Cathode for LED
2	GND	Ground
3	Vout2	Output Voltage 2
4	Vout1	Output Voltage 1
5	V <sub>CC</sub>	Power Supply
6	Anode (LED)	Anode for LED



## **■ORDERING INFORMATION**

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ(pcs)
NJL5820R	COBP	yes	yes	Au	No marking	8.9	3,000



## **■ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNIT			
Emitter						
Forward Current (Continuous)	I <sub>F</sub>	30	mA			
Reverse Voltage (Continuous)	$V_R$	6	V			
Power Dissipation	$P_{D}$	45	mW			
Detector(PDIC)						
Supply Voltage	V <sub>CC</sub>	6.0	V			
Power Dissipation	P <sub>PDIC</sub>	5	mW			
Coupled						
Total Power Dissipation	P <sub>tot</sub>	50	mW			
Operating Temperature	T <sub>opr</sub>	-30 to +85	°C			
Storage Temperature	T <sub>stg</sub>	-40 to +100	°C			
Reflow Soldering Temperature	T <sub>sol</sub>	255	°C			

## **■RECOMMENDATION OPERATING CONDITION**

PARAMETER	SYMBOL	VALUE	UNIT
Forward current	I <sub>F</sub>	2 to 10	mA
Supply voltage	$V_{CEO}$	+2.7 to +5.5	V
Distance between sensor and reflector	Gap	0.5 to 1.5	mm

## **■ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)**

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
mitter	•		•			
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =5mA	1.1	1.4	1.7	V
Revers Voltage	I <sub>R</sub>	V <sub>R</sub> =6V	1	-	10	μA
Peak wavelength	$\lambda_{P}$		-	940	-	nm
Detector						
Supply Voltage	$V_{CC}$		2.7	3.0	5.5	V
Operating Current	I <sub>CC</sub>	V <sub>CC</sub> =3V, In the dark	-	100	300	μΑ
Coupled						
Minimum Operating	I	V <sub>CC</sub> =3.0V,d=0.5mm	1	-	-	mA
Current	I <sub>Fmin</sub>					
High Level Output	V <sub>O</sub> H	$I_F$ =2mA, $V_{CC}$ =3.0V,d=0.5mm	V <sub>CC</sub> -	_	_	V
Voltage	A OI I	(reflector surface) *1	0.5	_	_	V
Low Level Output	V <sub>O</sub> L	$I_F$ =2mA, $V_{CC}$ =3.0V,d=0.5mm	_	_	GND	V
Voltage	v <sub>O</sub> L	(non-reflector surface) *1	_	_	+ 0.5	V
Phase Difference of	$V_P$	$I_{\rm F}=2$ mA, $V_{\rm CC}=3.0$ V,d=0.5mm	_	90	_	deg.
output Voltage	٧P	IF=2111A, V <sub>CC</sub> =3.0 V,u=0.3111111	_	90	_	ueg.
Duty ratio	Duty	$I_F$ =2mA, $V_{CC}$ =3.0V,d=0.5mm	-	50	-	%
Rise Time	t <sub>r</sub>		-	0.1	-	µsec
Fall Time	t <sub>f</sub>		-	0.1	-	µsec

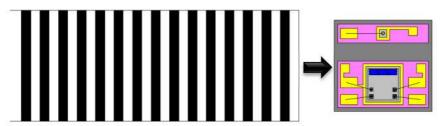
<sup>\*1:</sup> NJRC recommend the stripe reflector with 0.25mm strip and 0.25mm space.

In the Electro-Optical characteristics table, items that are showed only the typical value are not tested in manufacturing process.



## **■**METHOD OF THE OUTPUT VOLTAGE MEASUREMENT

Output voltage measures with NJRC recommended mirror.

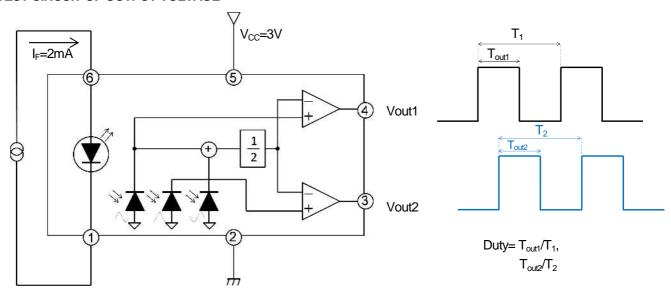


Strip mirror with PET film (0.25mm strip / 0.25mm space)

\* Meltec Co.,Ltd.

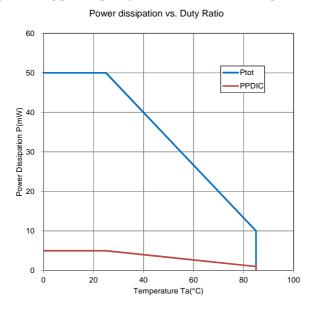


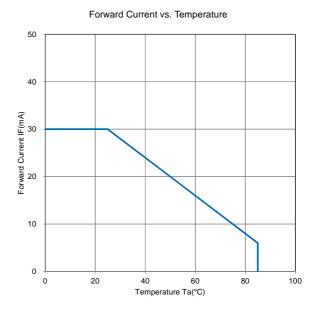
## **■TEST CIRCUIT OF OUTPUT VOLTAGE**



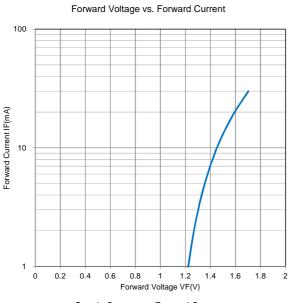


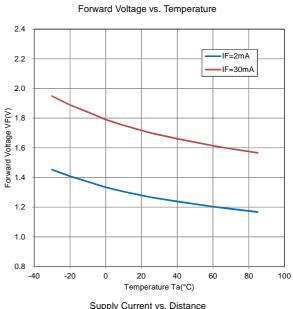
## **■POWER DISSIPATION vs. AMBIENT TEMPERATURE**

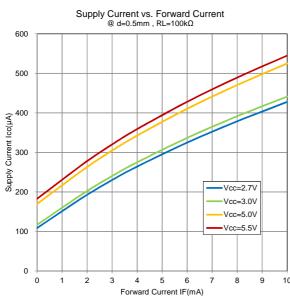


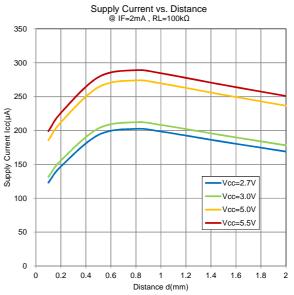


## **■TYPICAL CHARACTERISTICS (Ta=25°C)**



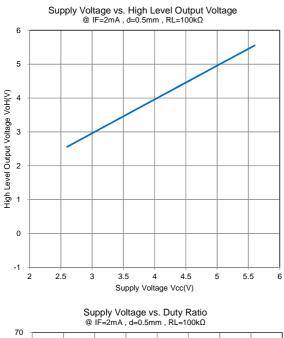


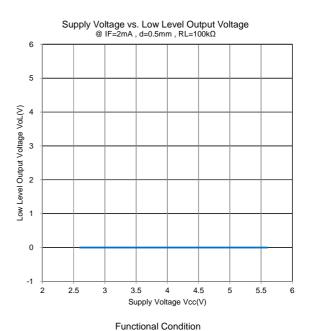


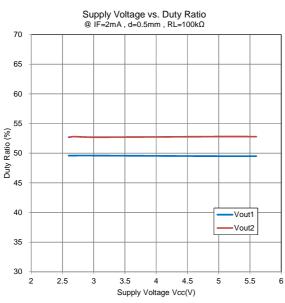


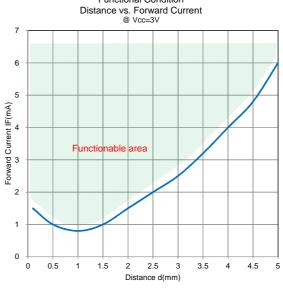


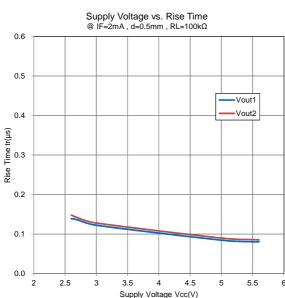
## ■TYPICAL CHARACTERISTICS (Ta=25°C)

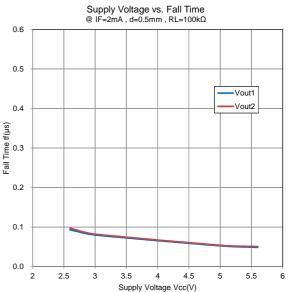






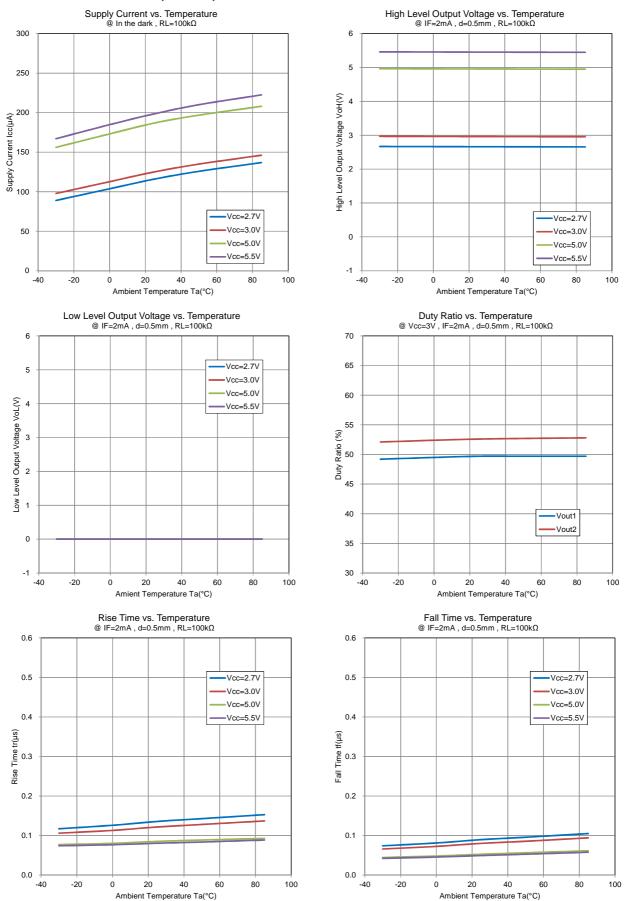








## ■TYPICAL CHARACTERISTICS (Ta=25°C)





## **■APPLICATION NOTE**

## (1) Attention in handling

Treat not to touch the light receiving and light emitting part.

Avoid to adhering the dust and any other foreign materials on the light receiving and light emitting part when using. When LED has operated by voltage, it should be connected the resistor of current adjustment. Avoid to applying direct voltage to LED, because there is possibility that LED is destroyed.

When mounting, special care has to be taken on the mounting position and tilting of the device because it is very important to place the device to the optimum position to the object.

#### (2) Attention in designing

Avoid the entering ambient light into light receiving part for avoid the malfunction by ambient light. Furthermore, there is possibility of malfunction when there are the other mounted parts by near this product peripheral.

There will be changing characteristics by detection object. Refer to this datasheet and evaluate by actual detection object.

When LED has been applied continuous power on long period of time, the output current is dropped. If it uses by always applying power to LED, have to consider the circuit designing of including output current decrease.

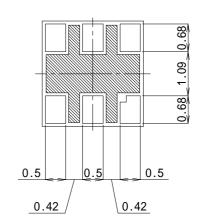


## **■PACKAGE OUTLINE** UNIT (mm)

## **TOP VIEW**

# 9 $0.8 \pm 0.15$ (0.87) (1.63)2.5

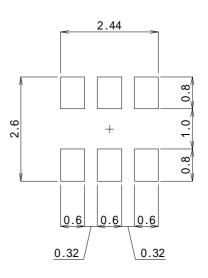
## **SIDE VIEW**



**BOTTOM VIEW** 

- 1: Cathode(LED)
- 2: GND
- 3: Vout2
- 4: Vout1
- 5: V<sub>CC</sub>
- 6: Anode(LED)

Unspecified tolerance: ±0.1mm



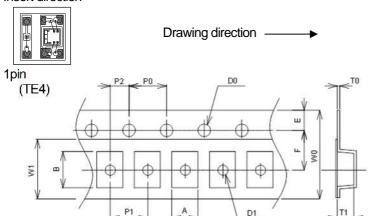
Foot Pattern



#### **■PACKING SPECIFICATION**

PACKING DIMENTIONS UNIT: mm

Insert direction



SYMBOL	DIMENSION	REMARK
Α	2.85±0.10	BOTTOM DIMENNSION
В	2.95±0.10	BOTTOM DIMENNSION
D0	φ1.50±0.10	
D1	φ1.05±0.10	
Е	1.75±0.10	
F	3.50±0.10	
P0	4.00±0.10	
P1	4.00±0.10	
P2	2.00±0.10	
T0	0.20±0.10	
T1	1.20±0.10	
W0	8.0+0.3/-0.1	
W1	(5.5)	THICKNESS 0.1MAX.

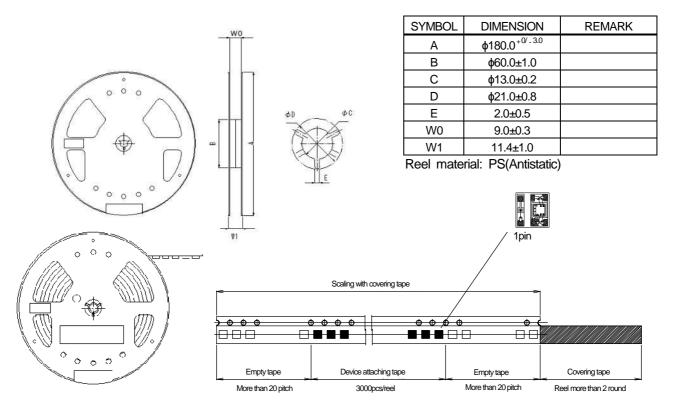
Carrier tape material: PC(Antistatic) Cover tape material: PETP(Antistatic)

#### **■TAPING STRENGTH**

There is a peel strength in the range of 0.2 to 0.7N when was peeled at a rate of 300mm per minute in opening angle 165 to 180° between the carrier tape and the cover tape.

## **■PACKAGING**

- 1) The taped products are to be rolled up on the taping reel as on the drawing.
- 2) Rolling up specification
  - 2-1) Start rolling : Carrier tape open space more than 20 Pieces.
  - 2-2) End of rolling : Carrier tape open space more than 20 Pieces, and 2 round of reel space at the cover tape only.
- 3) Taping quantity : 3,000 Pieces
- 4) Seal off after putting each reels in a damp proof bag with silica gel.





#### **■RECOMMENDED MOUNTING METHOD**

NOTE

Mounting was evaluated with the following profiles in our company, so there was no problem.

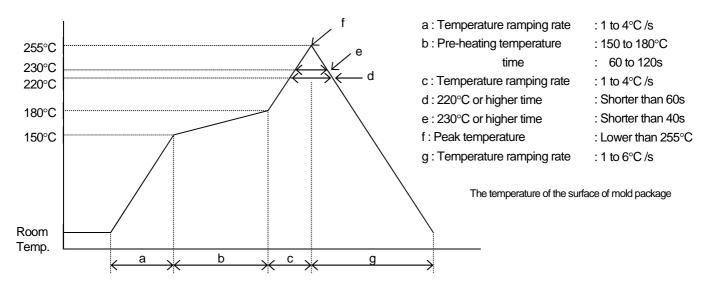
However, confirm mounting by the condition of your company beforehand.

The exposure of device under higher temperature many affect to the reliability of the products, it is recommended to complete soldering in the shortest time possible.

Mounting: Two Times soldering is allowed.

#### **■INFRARED REFLOW SOLDERING METHOD**

Recommended reflow soldering procedure



(NOTE1) Using reflow furnace with short wave infrared radiation heater such as halogen lamp

Regarding temperature profile, please refer to those fo reflow furnace.

In this case the resin surface temperature may become higher than lead terminals due to endothermic ally of black colored mold resin. Therefore, please avoid from direct exposure to mold resin.

## (NOTE2) Other method

Such other methods of soldering as dipping the device into melted solder and vapor phase method (VPS) are not appropriate because the body of device will be heated rapidly. Therefore, these are not recommended to apply.

(NOTE3) The resin gets softened right after soldering, so, the following care has to be taken

Not to contact the lens surface to anything.

Not to dip the device into water or any solvents.

#### **■FLOE SOLDERING METHOD**

Flow soldering is not possible.

## **IRON SOLDERING METHOD**

Iron soldering is not possible.



#### **■CLEANING**

Avid washing the device after soldering by reflow method.

#### **IC STORAGE CONDITIONS AND ITS DURATION**

(1) Temperature and humidity ranges

Pack Sealing Temperature: 5 to 40 [°C]

Humidity: 40 to 80 [%]

Pack Opening Temperature: 5 to 30 [°C]

Humidity: 40 to 70 [%]

After opening the bag, solder products within 48h.

Avoid a dry environment below 40% because the products are is easily damageable by the electrical discharge.

Store the products in the place where it does not create dew with the products due to a sudden change in temperature.

- (2) When baking, place the reel vertically to avoid load to the side.
- (3) Do not store the devices in corrosive-gas atmosphere.
- (4) Do not store the devices in a dusty place.
- (5) Do not expose the devices to direct rays of the sun.
- (6) Do not allow external forces or loads to be applied to IC's.
- (7) Be careful because affixed label on the reel might be peeled off when baking.
- (8) The product is recommended to do the baking before using for the stability of the quality.

#### **■BAKING**

In case of keeping expect above condition be sure to apply baking.

Baking method: Ta=60°C, 48 to 72h, One time baking is allowed

#### **■STORAGE DURATION**

Within a year after delivering this device.

For the products stored longer than a year, confirm their terminals and solderability before they are used.

#### **■**MOISTURE SENSITIVITY LEVELS

JEDEC: Level 5



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